



S E M I C O N D U C T O R

SR5250

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 250Volts

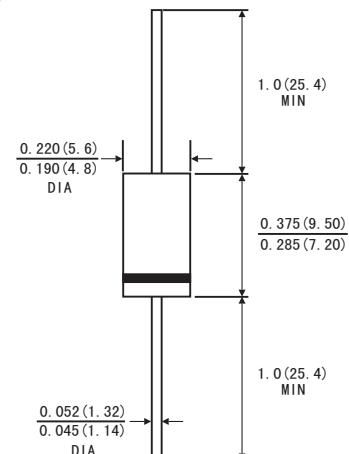
Forward Current - 5.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU



DO-201AD



Dimensions in inches and (millimetres)

MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041ounce, 1.15 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	SR 5250	Units	
Maximum repetitive peak reverse voltage	V _{RRM}	250	Volts	
Maximum RMS voltage	V _{RMS}	175	Volts	
Maximum DC blocking voltage	V _{DC}	250	Volts	
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I _(AV)	5.0	Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _J)	I _{FSM}	150.0	Amps	
Maximum instantaneous forward voltage at 5.0 A(Note 1)	V _F	0.95	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T _A =25°C	IR	20	A
	T _A =125°C	IR	3	mA
Typical junction capacitance(Note 3)	C _J	400	pF	
Typical thermal resistance (Note 2)	R _{θJA} R _{θJL}	25.0 8.0	°C/W	
Operating junction temperature range	T _J	-65 to+150	°C	
Storage temperature range	T _{STG}	-65 to+150	°C	

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.375"(9.5mm)lead length

3.Measured at 1MHz and reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES SR5250

FIG.1-FORWARD CURRENT DERATING CURVE

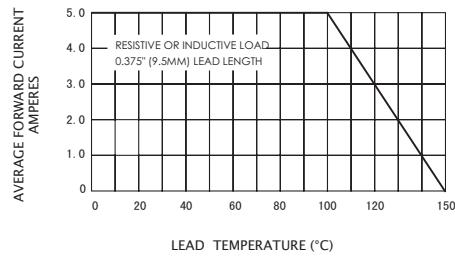


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

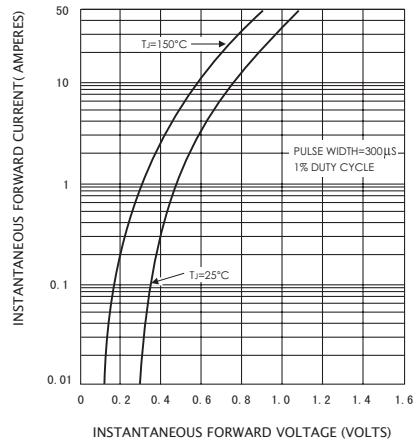
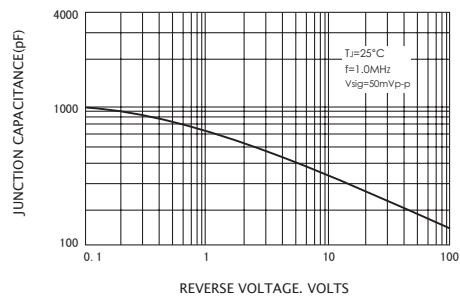


FIG.5-TYPICAL JUNCTION CAPACITANCE



JINAN JINGHENG ELECTRONICS CO., LTD.

FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

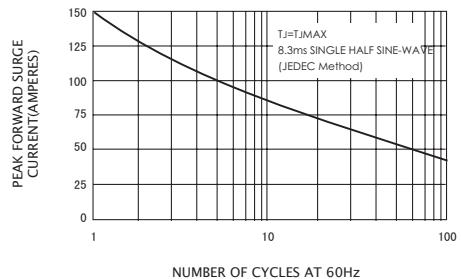
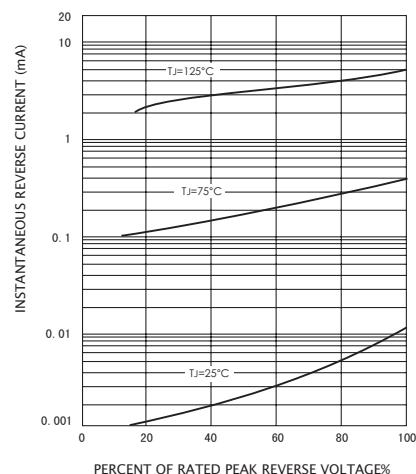


FIG.4-TYPICAL REVERSE CHARACTERISTICS



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